## **ELECTRONIC INFORMATION DISCLOSURE STATEMENT**

Electronic Version v18

Stylesheet Version v18.0

Title of Invention

METHOD FOR FABRICATING A NITRIDED SILICON-OXIDE GATE DIELECTRIC

Application Number:

10/604905

**Confirmation Number:** 

8-26-03

First Named Applicant:

Jay Burnham

Attorney Docket Number:

BUR920020109US1

Art Unit:

2813

Examiner:

Search string:

( 6399445 or 6380056 or 6368923 or 6335252 or 6291867 or 6200651 or 6114258

or 6136654 or 6171911 or 6027977 or 5726087 or 5648284 or 5596218 or 5445999

or 5219773 or 4621277 ).pn

## **US Patent Documents**

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

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init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
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## **Signature**

Examiner Name	Date
2122	10/24/05

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